

Description

The 74LVCE1G86 is a single 2-input positive EXCLUSIVE OR gate with a standard totem pole output. The device is designed for operation with a power supply range of 1.4V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

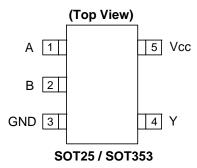
The gate performs the positive Boolean function:

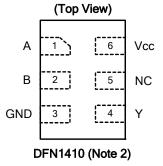
$$Y = A \oplus B$$
 or $Y = \overline{A}B + A\overline{B}$

Features

- Extended Supply Voltage Range from 1.4 to 5.5V
- Switching speed characterized for operation at 1.5V
- Offers 30% speed improvement over LVC at 1.8V.
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 Exceeds 200-V Machine Model (A115-A)
 Exceeds 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- Direct Interface with TTL Levels
- SOT25, SOT353 and DFN1410: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

Pin Assignments





Applications

- Voltage Level Shifting
- Bus Driver / Repeater
- Parity Bit Generation
- · Selectable signal Inverter
- Power Down Signal Isolation
- General Purpose Logic
- Wide array of products such as.
 - o PCs, networking, notebooks, netbooks, PDAs
 - o Computer peripherals, hard drives, CD/DVD ROM
 - o TV, DVD, DVR, set top box
 - o Cell Phones, Personal Navigation / GPS
 - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

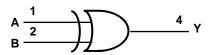
2. Pin 2 and pin 5 of the DFN1410 package are internally connected.



Pin Descriptions

Pin Name	Description			
Α	Data Input			
В	Data Input			
GND	Ground			
Y	Data Output			
Vcc	Supply Voltage			

Logic Diagram



Function Table

Inp	Output	
Α	В	Y
Η	Η	L
L	Н	Н
Н	L	Н
L	L	L



Absolute Maximum Ratings (Note 3)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	٧
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	٧
Vo	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to 6.5	٧
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I <0	-50	mA
I _{OK}	Output Clamp Current	-50	mA
Io	Continuous output current	±50	mA
	Continuous current through Vdd or GND	±100	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Note: 3. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 4)

Symbol		Parameter	Min	Max	Unit
\ /	On anoting Naltage	Operating	1.4	5.5	V
V_{CC}	Operating Voltage	Data retention only	1.2		V
		$V_{CC} = 1.4 \text{ V to } 1.95 \text{ V}$	0.65 X V _{CC}		
\ /	Lligh lovel langet Valtage	V _{CC} = 2.3 V to 2.7 V	1.7		V
V_{IH}	High-level Input Voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2		V
		V _{CC} = 4.5 V to 5.5 V	0.7 X V _{CC}		
		$V_{CC} = 1.4 \text{ V to } 1.95 \text{ V}$		0.35 X V _{CC}	
\ /	L our lovel input voltoge	V _{CC} = 2.3 V to 2.7 V		0.7	V
V_{IL}	Low-level input voltage	V _{CC} = 3 V to 3.6 V		0.8	V
		V _{CC} = 4.5 V to 5.5 V		0.3 X V _{CC}	
Vı	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
	High-level output current	Vcc=1.4 V		-3	
		V _{CC} = 1.65 V		-4	mA
		V _{CC} = 2.3 V		-8	
I _{OH}		V _{CC} = 3 V		-16	
				-24	
		V _{CC} = 4.5 V		-32	
		Vcc=1.4 V		3	
		V _{CC} = 1.65 V		4	
	Lave lavel autout aumont	V _{CC} = 2.3 V		8	mA
I _{OL}	Low-level output current	V 2.V		16	
		$V_{CC} = 3 V$		24	
		V _{CC} = 4.5 V		32	
		$V_{CC} = 1.4 \text{ to } 3V$		20	
$\Delta t/\Delta V$	Input transition rise or fall	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V
	rate	$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		5	
T _A	Operating free-air temperature		-40	85	°C

Note: 4. Unused inputs should be held at Vcc or Ground.



Electrical Characteristics (All typical values are at Vcc = 3.3V, T_A = 25°C)

Over recommended free-air temperature range (unless otherwise noted)

Symbol	Parameter	Test Conditions	Vcc	Min	Тур.	Max	Unit
		I _{OH} = -100μA	1.4 V to 5.5V	V _{CC} - 0.1			
		$I_{OH} = -3mA$	1.4 V	1.05			
		$I_{OH} = -4mA$	1.65 V	1.2			
V_{OH}	High Level Output Voltage	$I_{OH} = -8mA$	2.3V	1.9			V
	I _{OH} = -16mA 3 V	2.4					
		$I_{OH} = -24mA$	3 V	2.3			
		$I_{OH} = -32mA$	4.5 V	3.8			
		$I_{OL} = 100 \mu A$	1.4 V to 5.5V			0.1	
		$I_{OL} = 3mA$	1.4 V			.4	
		$I_{OL} = 4mA$	1.65 V			0.45	
V _{OL} H	High-level Input Voltage	$I_{OL} = 8mA$	2.3V			0.3	V
		$I_{OL} = 16mA$	3 V			0.4	
		$I_{OL} = 24mA$	3 V			0.55	
		$I_{OL} = 32mA$	4.5			0.55	
l _l	Input Current	$V_1 = 5.5 \text{ V or GND}$	0 to 5.5 V			± 5	μΑ
I _{OFF}	Power Down Leakage Current	V_1 or $V_0 = 5.5V$	0			± 10	μA
I _{cc}	Supply Current	$V_1 = 5.5V$ of GND $I_0=0$	1.4 V to 5.5V			10	μA
ΔI _{CC}	Additional Supply Current	One input at V _{CC} – 0.6 V Other inputs at V _{CC} or GND	3 V to 5.5V			500	μA
C _i	Input Capacitance	$V_i = V_{CC} - \text{ or GND}$	3.3		3.5		pF
	T	SOT25	(Note 5)		204		
θ_{JA}	Thermal Resistance Junction-to-Ambient SOT353 DFN1410	SOT353	(Note 5)		371		°C/W
		DFN1410	(Note 5)		430		1
		SOT25	(Note 5)		52		
θ_{JC}	Thermal Resistance	SOT353	(Note 5)		143		°C/W
	Junction-to-Case	DFN1410	(Note 5)		190		

Note: 5. Test condition for SOT25, SOT353, and DFN1410: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



Switching Characteristics

Over recommended free-air temperature range, CL = 15pF (see Figure 1)

Parameter	From	то	TO ± 0.1V ± 0.15V		Vcc = 2.5 V V ± 0.2V		Vcc = 3.3 V ± 0.3V		Vcc = 5 V ± 0.5V		Unit		
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	A or B	Υ	2.1	9.1	1.4	6.3	0.8	3.6	0.6	3.2	0.7	2.9	ns

Over recommended free-air temperature range, CL = 30 or 50pF as noted (see Figure 2)

Parameter	From	то	Vcc = ± 0			: 1.8 V .15V		: 2.5 V).2V		3.3 V 3.3 V	Vcc :	= 5 V).5V	Unit
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	A or B	Y	3.5	9.9	2.4	6.9	1.4	4.4	1	4.1	0.9	3.6	ns

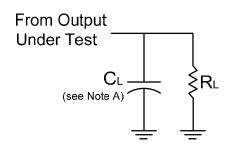
Operating Characteristics

 $T_A = 25$ °C

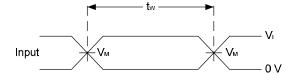
Parameter		Test	Vcc = 1.5 V	Vcc = 1.8 V	Vcc = 2.5 V	Vcc = 3.3 V	Vcc = 5 V	Unit
_	Conditi		TYP	TYP	TYP	TYP	TYP	
C _{pd}	Power dissipation capacitance	f = 10 MHz	22	22	22	22	24	pF



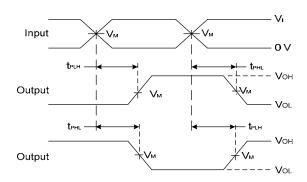
Parameter Measurement Information



Vcc	In	outs	V	6		
VCC	Vı	t _r /t _f	V _M	CL	R_L	
1.5V±0.1V	V _{CC}	≤2ns	V _{CC} /2	15pF	1ΜΩ	
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	15pF	1ΜΩ	
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	15pF	1ΜΩ	
3.3V±0.3V	3V	≤2.5ns	1.5V	15pF	1ΜΩ	
5V±0.5V	V _{cc}	≤2.5ns	V _{CC} /2	15pF	1ΜΩ	



Voltage Waveform Pulse Duration



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.

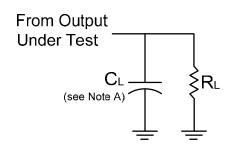
C. Inputs are measured separately one transition per measurement.

D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$

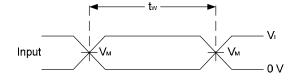
Figure 1. Load Circuit and Voltage Waveforms



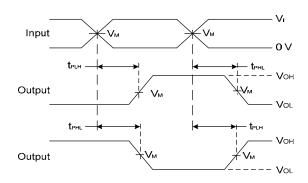
Parameter Measurement Information (Continued)



Vcc	Inp	outs	V _M	CL	R_L
	Vı	t _r /t _f	· · · · · · · · · · · · · · · · · · ·	J.	
1.5V±0.15	V _{CC}	≤2ns	V _{CC} /2	30pF	1ΚΩ
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	30pF	1ΚΩ
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	30pF	500Ω
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	50pF	500Ω



Voltage Waveform Pulse Duration



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.

C. Inputs are measured separately one transition per measurement.

D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$

Figure 2. Load Circuit and Voltage Waveforms



Ordering Information

T4LVCE1G 86 XXX - 7

Logic Device Function Package Packing

74: Logic Prefix 86: 2-Input W5: SOT25 7: Tape & Reel

SE: SOT353

FZ4: DFN1410

LVCE: 1.4 to 5.5V XOR-Gate Family

1G : One gate

	Device	Package	Packaging	7" Tape a	nd Reel
	Device	Code	(Note 5)	Quantity	Part Number Suffix
Pb ,	74LVCE1G86W5-7	W6	SOT25	3000/Tape & Reel	-7
Pb ,	74LVCE1G86SE-7	SE	SOT353	3000/Tape & Reel	-7
Pb ,	74LVCE1G86FZ4-7	FZ4	DFN1410	5000/Tape & Reel	-7

Note: 6. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



Marking Information

(1) SOT25 and SOT353

(Top View)

5 4 xx y w x

2

3

1

XX: Identification code

Y: Year 0~9

 \underline{W} : Week : A $^{\sim}$ Z : 1 $^{\sim}$ 26 week;

a~z: 27~52 week; z represents

52 and 53 week

 \underline{X} : A $^{\sim}$ Z: Internal code

Part Number	Package	Identification Code
74LVCE1G86W5	SOT25	PX
74LVCE1G86SE	SOT353	PX

(2) DFN1410

(Top View)

 XX: Identification Code

Y: Year: 0~9

<u>W</u>: Week: A~Z: 1~26 week;

a~z: 27~52 week; z represents 52 and 53 week

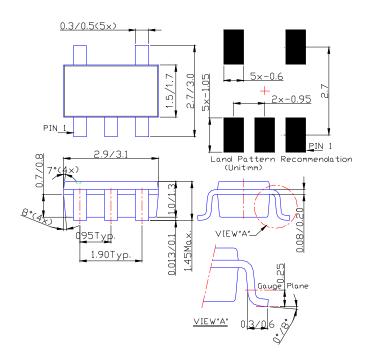
 \underline{X} : A~Z: Internal code

Part Number	Package	Identification Code
74LVCE1G86FZ4	DFN1410	PX

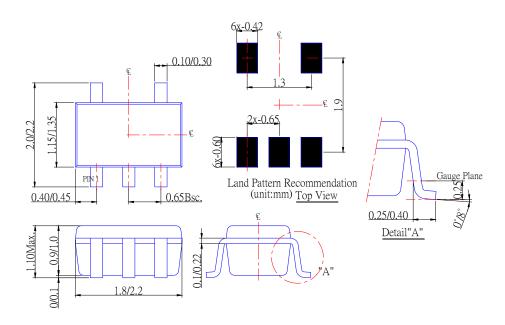


Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



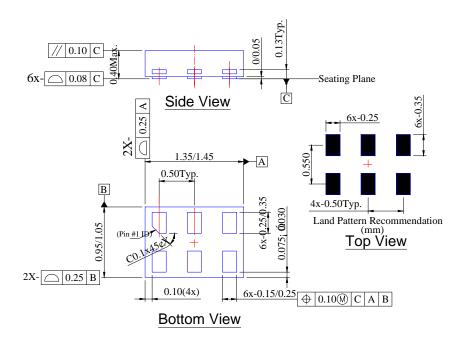
(2) Package Type: SOT353





Package Outline Dimensions (All Dimensions in mm)

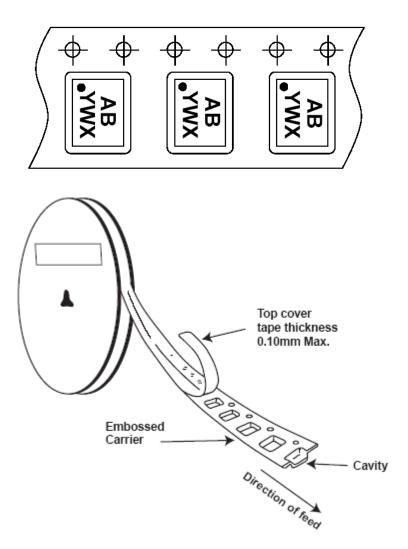
(3) Package Type: DFN1410





Taping Orientation (Note 7)

For DFN1410



Note: 7. The taping orientation of the other package type can be found on our website at http://www.diodes.com/datasheets/ap02007.pdf



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NLVVHC1G14DTT1G NLX2G08DMUTCG NLX2G08MUTCG MC74HCT20ADR2G 091992B 091993X 093560G 634701C 634921A
NL17SG32P5T5G NL17SG86DFT2G NLU1G32CMUTCG NLV14001UBDR2G NLVVHC1G132DTT1G NLVVHC1G86DTT1G
NLX1G11AMUTCG NLX1G97MUTCG 746427X 74AUP1G17FW5-7 74LS38 74LVC1G08Z-7 74LVC32ADTR2G 74LVC1G125FW4-7
74LVC08ADTR2G MC74HCT20ADTR2G NLU1G08CMX1TCG NLV14093BDTR2G NLV17SZ00DFT2G NLV17SZ02DFT2G
NLV17SZ126DFT2G NLV27WZ17DFT2G NLV74HC02ADR2G NLV74HC08ADR2G NLVVHC1GT32DFT1G 74HC32S14-13 74LS133
74LVC1G32Z-7 M38510/30402BDA 74LVC1G86Z-7 74LVC2G08RA3-7 M38510/06202BFA NLV74HC08ADTR2G
NLV74HC14ADR2G